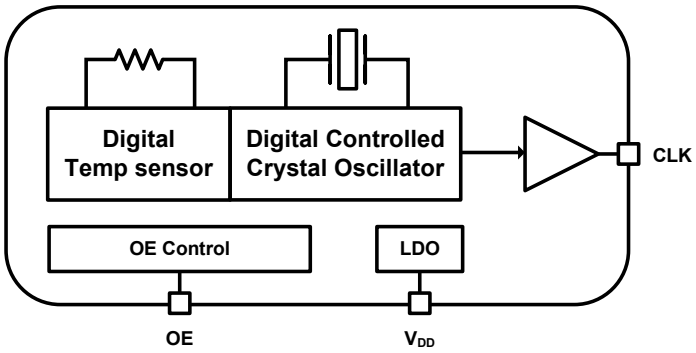
AS5211 Ultra Low Jitter LVCMOS TCXO

Description

The AS5211 is a temperature compensated crystal oscillator (TCXO) with a LVCMOS output clock between 10 MHz and 76.8 MHz. The AS5211 utilizes digital temperature sensing and frequency compensation technologies to provide a high precision, temperature stabilized clock with grade options from ±0.5ppm to ±20ppm.

The AS5211 operates in a wide power supply range from 1.8V to 3.3V. The on-chip LDOs ensure robust power supply noise rejection which simplifies the external supply noise filtering requirements.

Available in industry-standard 2520, 3225, 5032 packages, the AS5211 comes in industrial, extended industrial and automotive device grades. Specific combination of package, frequency, stability, driver format, and device grade can be selected at the time of ordering.



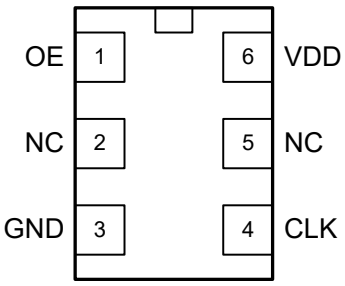
Key Features

- Frequency range: 10 to 76.8 MHz
- Standard LVCMOS output
- Ultra-low jitter: 93 fs Typ RMS
  (12 kHz – 20 MHz, @76.8 MHz)
- Operating temperature range:
  - -40 to 85 ℃ (Industial grade)
  - -40 to 105 ℃ (Extended-Industial grade)
  - -40 to 105 ℃ (AEC-Q100 grade 2)
- Temperature stability:
  - ±0.5 ppm (Grade C)
  - ±20 ppm (Grade D)
- Integrated LDO for on-chip power supply noise filtering
- Support 1.8V, 2.5V, 3.3V V_{DD} supply operation
- Standard DFN 2520, 3225 and 5032 packages

Application

- Precision GNSS systems
- Microwave backhaul
- Narrow-band communications
- Storage and servers
- Test and measurements

Pin definition



Top view

Pin#	Description
1	OE = Output enable. Active high
2	NC = Not connect
3	GND = Ground
4	NC = Not connect
5	CLK = Clock output
6	VDD = Power supply

1. Ordering Guide

XO Series	Description
5211	CMOS-output TCXO

	Device Type
A	General
X[1]	Factory defined setting

	Temperature Stability Grade
C	+/- 0.5ppm
D[2]	+/- 20ppm

	Device Grade	Temperature Grade
I	Industrial grade	-40 to 85°C
E[3]	Extended industrial grade	-40 to 105°C
A[3]	Automotive grade	-40 to 105°C

Device Revision

5211 | A | A | A | C | - | - | - | - | - | - | - | - | A | A | I | T

	Output Format	Power Supply
A	LVCMOS	3.3 V
B	LVCMOS	2.5 V
C	LVCMOS	1.8 V

	Pin #1
A	OE Active High
C	OE Active Low

Frequency Code[4]	Description
xxMxxxxx	10 MHz <= FCLK <= 76.8 MHz

	Package
A	5032
B	3225
C	2520

Code	Packing type	Qty
T	7-inch reel	250
R	13-inch reel	2500
F	13-inch reel	5000
<blank>	Bulk	Sample

Note:

1. “X” refers to the ID for the unique configuration with factory-defined settings, the value ranges from “B” to “Z”.
2. Temperature compensation is not applied for grade-D device. Frequency is calibrated at 25 ℃ in production test.
3. Contact Aeonsemi for “Extended industrial” and “Automotive” grade device.
4. For example: 38.4 MHz = 38M40000; 76.8 MHz = 76M80000.

2. Electrical Specifications

Table 2.1. Electrical Specifications

Parameter	Symbol	Min	Typ	Max	Unit	Note
Operating Temperature Range						
Temperature Range	T_A	-40	–	85	℃	Industrial grade
		-40	–	105	℃	Extended industrial grade
		-40	–	105	℃	Automotive AEC-Q100 Grade2
Supply Voltage and Power Consumption						
Supply Voltage	V_{DD}	1.62	–	3.63	V	Core voltage
Supply Current (F_{CLK} = 38.4 MHz)	I_{CORE}	–	4	5	mA	Tristate Hi-Z (Output disabled)
	I_{DRV}	–	6	8	mA	1.8V LVCMOS (C_L=15pF)
		–	8	10	mA	2.5V LVCMOS (C_L=15pF)
		–	10	13	mA	3.3V LVCMOS (C_L=15pF)
Frequency Range						
Frequency Range	F_{CLK}	10	–	76.8	MHz	Standard frequency options
		10, 16, 19.2, 20, 25, 26, 32, 38.4, 50, 52				Contact Aeonsemi for other frequency options
Frequency Tolerance						
Initial frequency accuracy[1]	F_{INIT}	-2	–	2	ppm	Grade C
		-5	–	5	ppm	Grade D
Temperature stability over full temp range[2]	F_{STAB}	-0.5	–	0.5	ppm	Grade C
		-20	–	20	ppm	Grade D
Aging	S_{AGING}	-1	–	1	ppm/y	Maximum aging slope at 25 ℃
	F_{AGING}	-3	–	3	ppm	10-year aging at 25℃
Notes: 1. Inclusive of initial frequency tolerance at 25℃, variations over supply voltage, load and humidity after 2 times of reflows. 2. Frequency / temperature characteristics with offset removed.						
IO Characteristics						
Output enable (OE)	V_{IH}	0.7×V_{DD}	–	–	V	Input high voltage
	V_{IL}	–	–	0.3×V_{DD}	V	Input low voltage
	R_{PUP}	–	50	–	kΩ	Internal pull-up resistor to V_{DD}
	T_D	–	–	3	us	Output disable time, F_{CLK} >10 MHz
	T_E	–	–	20	us	Output enable time, F_{CLK} >10 MHz

Continued on next page

Parameter	Symbol	Min	Typ	Max	Unit	Note
Output Characteristics						
Powerup time	T_{OSC}	–	–	4	ms	Time from power reaches 0.9 × V_{DD} to output frequency (F_{CLK}) within spec
Duty cycle	DC	45	–	55	%	LVCMOS (C_L=15pF)
Rise/Fall time (20% to 80% VPP)	$T_{R/F}$	–	0.5	1.5	ns	LVCMOS (C_L=15pF)
LVCMOS	V_{OH}	0.83×V_{DD}	–	–	V	C_L=15pF
	V_{OL}	–	–	0.17×V_{DD}	V	
Phase Noise and Jitter						
RMS jitter	R_J	–	100	200	fs	F_{CLK} >= 50 MHz
BW: 12k - 20MHz		–	150	300	fs	F_{CLK} <50 MHz
Phase noise	PN_{10}	–	-89	–	dBc/Hz	Phase noise at 10Hz offset
38.4MHz LVCMOS output	PN_{100}	–	-119	–	dBc/Hz	Phase noise at 100Hz offset
V_{DD} = 1.8 - 3.3V	PN_{1k}	–	-143	–	dBc/Hz	Phase noise at 1kHz offset
	PN_{10k}	–	-152	–	dBc/Hz	Phase noise at 10kHz offset
	PN_{100k}	–	-158	–	dBc/Hz	Phase noise at 100kHz offset
	PN_{1M}	–	-162	–	dBc/Hz	Phase noise at 1MHz offset
	PN_{10M}	–	-163	–	dBc/Hz	Phase noise at 10MHz offset
PSNR						
Spurs from power noise	PSNR	–	-76	–	dBc	100 kHz sine wave
50mV ripple		–	-75	–	dBc	200 kHz sine wave
V_{DD} = 1.8V		–	-75	–	dBc	500 kHz sine wave
		–	-75	–	dBc	1 MHz sine wave
Spurs from power noise	PSNR	–	-83	–	dBc	100 kHz sine wave
50mV ripple		–	-83	–	dBc	200 kHz sine wave
V_{DD} = 2.5 or 3.3V		–	-83	–	dBc	500 kHz sine wave
		–	-82	–	dBc	1 MHz sine wave

Table 2.2. Environmental Compliance and Package Information

Parameter	Value
Moisture sensitivity level (MSL)	3

Notes:

For additional product information not listed in the data sheet (e.g. RoHS Certifications, MSDS data, qualification data, REACH Declarations, ECCN codes, etc.), contact aeonsemi.com/contact_us

Table 2.3. Absolute Maximum Ratings[1]

Parameter	Symbol	Rating	Unit
Maximum operating temperature	T_{AMAX}	125	℃
Storage temperature	T_S	-55 - 125	℃
Supply voltage	V_{DD_MAX}	-0.5 - 3.8	V
Input voltage	V_{IN_MAX}	-0.5 - V_{DD}+0.3	V
ESD HBM (JESD22-A114)	HBM	4.0	kV
ESD CDM (JESD22-C101)	CDM	1.0	kV
Solder Temperature[2]	T_{PEAK}	260	℃
Solder time at T_{PEAK}[2]	T_P	20 - 40	sec

Notes:

1. Stresses beyond those listed in this table may cause permanent damage to the device. Functional operation specification compliance is not implied at these conditions. Exposure to maximum rating conditions for extended periods may affect device reliability.
2. The device is compliant with JEDEC J-STD-020.

3. Package Outline Drawing

Figure 3.1. shows the package outline drawing for the AS5211 devices. Details of dimension for different size options are listed in Table 3.1.

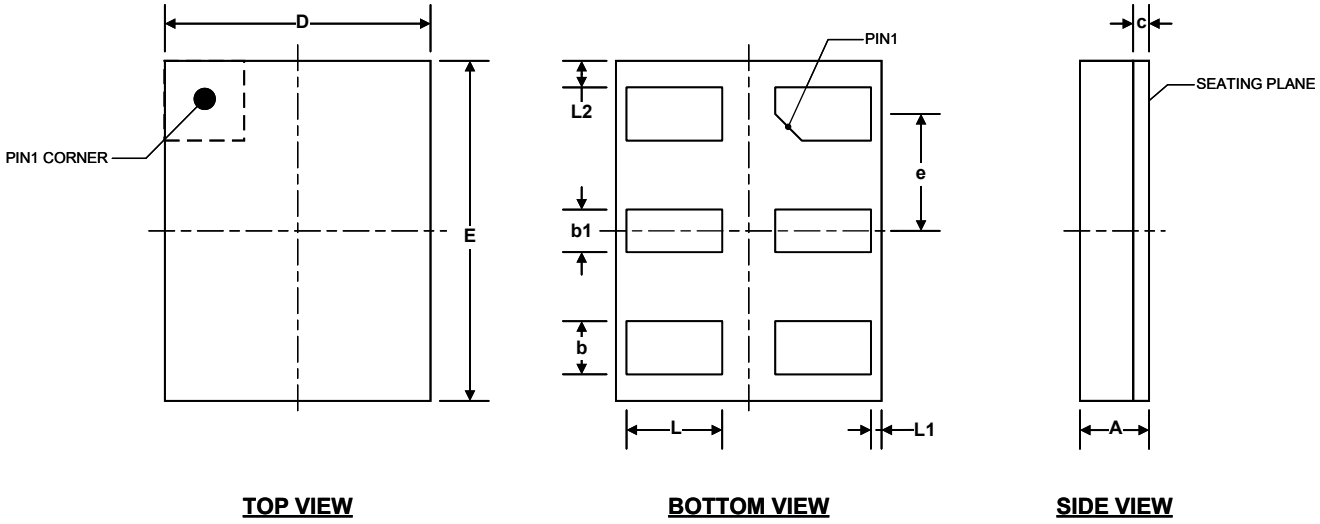


Figure 3.1. Package Outline Drawing

Table 3.1. Dimensions of Package Outline Drawing (mm)

Symbol	5032 Package	3225 Package	2520 Package
A	1.146 ± 0.100	1.146 ± 0.100	0.876 ± 0.100
b	0.640 ± 0.050	0.600 ± 0.050	0.380 ± 0.050
b1	0.640 ± 0.050	0.600 ± 0.050	0.380 ± 0.050
D	3.200 ± 0.100	2.500 ± 0.050	2.000 ± 0.050
e	1.270 BSC	1.100 BSC	0.900 BSC
E	5.000 ± 0.100	3.200 ± 0.050	2.500 ± 0.050
L	0.900 ± 0.075	0.700 ± 0.075	0.550 ± 0.075
L1	0.100 ± 0.075	0.100 ± 0.075	0.100 ± 0.075
L2	0.910 ± 0.075	0.200 ± 0.075	0.160 ± 0.075

4. Recommended PCB Land Pattern

Figure 4.1. shows the drawing of recommended PCB land pattern for the AS5211 devices. Details of dimension for different size options are listed in Table 4.1.

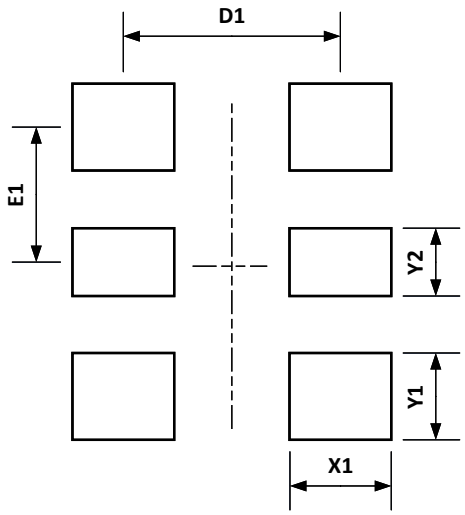


Figure 4.1. Recommended PCB Land Pattern

Table 4.1. Dimensions of Recommended PCB Land Pattern (mm)

Symbol	5032 Package	3225 Package	2520 Package
D1	2.20	1.70	1.35
E1	1.27	1.10	0.90
X1	1.20	1.00	0.85
Y1	0.84	0.80	0.58
Y2	0.84	0.80	0.58

Notes:

The following notes and stencil design are shared as recommendations only. A customer or user may find it necessary to use different parameters and fine-tune their SMT process as required for their application and tooling.

General

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. Dimensioning and Tolerancing is per the ANSI Y14.5M-1994 specification.
3. This Land Pattern Design is based on the IPC-7351 guidelines.
4. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a Fabrication Allowance of 0.05 mm.

Solder Mask Design

1. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.

Stencil Design

1. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
2. The stencil thickness should be 0.125 mm (5 mils).
3. The ratio of stencil aperture to land pad size should be 0.8 1 for the pads.

Card Assembly

1. A No-Clean, Type-3 solder paste is recommended.
2. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

5. Top Mark

Figure 5.1. shows the top mark specifications for the AS5211 devices. Description of each line is listed in Table 5.1.

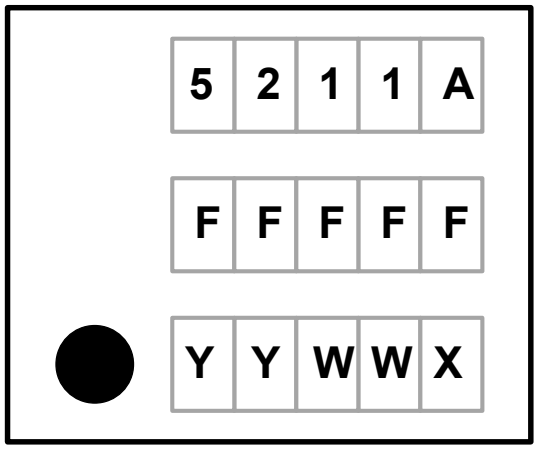


Figure 5.1. Top Mark

Table 5.1. Top Mark Description

Line	Position	Description
1	1-5	Device Name
2	1-5	Unique 5-digit Device Configuration Number
3	1	Pin 1 orientation mark (dot)
	2-3	Year (last two digits of the year), to be assigned by assembly site (ex: 2025 = 25)
	4-5	Calendar Work Week number (1-53), to be assigned by assembly site
	6	Manufacturer code

6. Packing Specification

Figure 6.1. shows the packing specifications for the AS5211 devices. Details of the tape specifications are listed in Table 6.1.
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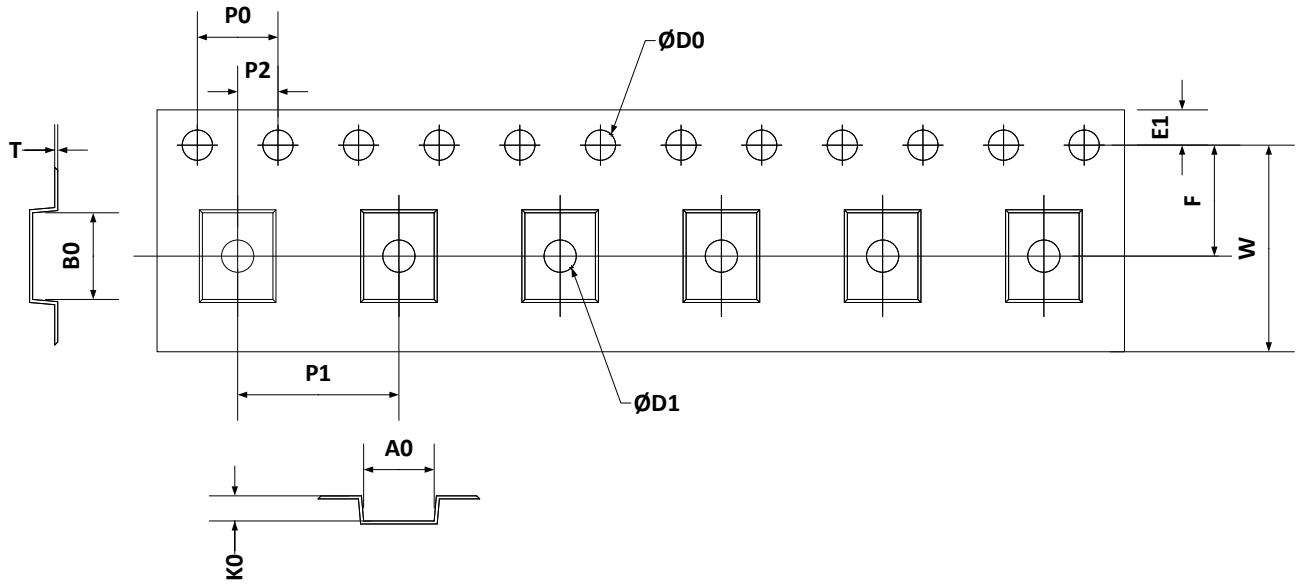

Figure 6.1. Tape Specification

Table 6.1. Dimensions of Tape (mm)

Symbol	5032 Package	3225 Package	2520 Package
A0	3.50 ± 0.10	2.80 ± 0.10	2.30 ± 0.10
B0	4.30 ± 0.10	3.50 ± 0.10	2.80 ± 0.10
K0	1.25 ± 0.10	1.05 ± 0.10	1.30 ± 0.10
E1	1.75 ± 0.10	1.75 ± 0.10	1.75 ± 0.10
F	5.50 ± 0.05	5.50 ± 0.05	5.50 ± 0.10
W	12.00 ± 0.30	12.00 ± 0.30	12.00 (+0.30/-0.10)
T	0.30 ± 0.05	0.30 ± 0.05	0.30 ± 0.05
P0	4.00 ± 0.10	4.00 ± 0.10	4.00 ± 0.10
P1	8.00 ± 0.10	8.00 ± 0.10	8.00 ± 0.10
P2	2.00 ± 0.05	2.00 ± 0.05	2.00 ± 0.10
ϕD0	1.50 ± 0.10	1.50 ± 0.10	1.50 (+0.10/-0)
ϕD1	1.60 ± 0.10	1.60 ± 0.10	1.05 ± 0.10

7. Important Notice and Disclaimer

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8. Revision History

Revision	Date	Description
1.06	Oct 2026	Updated ordering guide
1.05	Aug 2026	Removed paragraph first-line indentation Corrected top mark position table
1.03	Mar 2026	Updated the Top Mark Rule
1.02	Sep 2025	Corrected several description errors
1.01	Aug 2025	Officially release as mass production version
0.09	Feb 2025	Added frequency options; ”2520” package outline diagram
0.08	Aug 2024	Added ”5032” & ”3225” package outline diagram
0.07	Apr 2024	Added ”2520” package option
0.06	Feb 2024	Updated the ”Ordering guide”
0.05	Aug 2023	Revised the stability for D-grade option
0.04	Jul 2023	Updated the package outline
0.03	Jun 2023	Updated the ”Ordering guide” and added phase noise jitter for clock >=100 MHz
0.02	Feb 2023	Updated the ”Temperature Stability Grade” D grade
0.01	Nov 2021	Preliminary release